TOSHIBA Photocoupler GaAlAs Ired & Photo-Diode Array

# **TLP190B**

Telecommunications
Programmable Controllers
MOS Gate Drivers
MOSFET Gate Drivers

The TOSHIBA TLP190B mini-flat photocoupler is suitable for surface-mount assembly.

The TLP190B consists of a GaA $\ell$ As light emitting diode optically coupled to a series connected photodiode array which is suitable for MOSFET gate drivers.

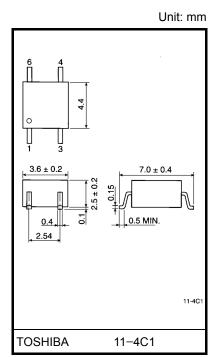
Open voltage: 7.0V (min)
Short current: 12.0 µA (min)
Isolation voltage: 2500 Vrms (min)
UL recognized: UL1577, file no. E67349

#### **Short Current**

Type Name	Classification	Short Current		Marking Of
Name	Classification	(min)	l <sub>F</sub>	Classification
TLP190B	C20	20 μΑ	10 mA	20
121 1002	Standard	12 µA	1011111	20, blank

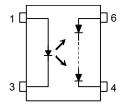
Note: Application type name for certification test, please use standard product type name, i.e.

TLP190B(C20): TLP190B



Weight: 0.09 g(typ.)

### Pin Configuration (top view)



- 1. Anode
- 3. Cathode
- 4. Cathode
- 6. Anode

### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	ΙF	50	mA
	Forward current derating (Ta $\geq$ 25°C) $\Delta I_F$ / °C		-0.5	mA / °C
LED	Pulse forward current (100µs pulse 100pps)	I <sub>FP</sub>	1	Α
	Reverse voltage	V <sub>R</sub>	3	V
	Junction temperature	Tj	125	°C
	Forward current	I <sub>FD</sub>	50	μΑ
Detector	Reverse voltage	$V_{RD}$	10	V
	Junction temperature	Tj	125	°C
Storage tem	perature range	T <sub>stg</sub>	-55 to 125	°C
Operating temperature range		T <sub>opr</sub>	-40 to 85	°C
Lead soldering temperature (10 s)		T <sub>sol</sub>	260	°C
Isolation vol (AC, 1 min.,	tage R.H. ≤ 60%) Note 1	BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	l <sub>F</sub>	_	20	25	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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# Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA	1.2	1.4	1.7	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 3 V	_	_	10	μΑ
LLD	Capacitance	C <sub>T</sub>	V = 0, f = 1 MHz	_	30	60	pF
	Forward voltage	V <sub>FD</sub>	Ι <sub>C</sub> = 10 μΑ	-	7	_	٧
Detector	Reverse current	I <sub>RD</sub>	V <sub>R</sub> = 10 V	_	1	_	nA
	Capacitance (anode to cathode)	C <sub>TD</sub>	V = 0, f = 1 MHz	_	_	_	pF

## **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Open voltage	V <sub>OC</sub>	I <sub>F</sub> = 10 mA	7	8	_	V
Short current	I <sub>SC</sub>	I <sub>F</sub> = 10 mA	12	20	_	μA

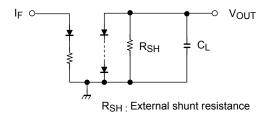
### **Isolation Characteristics (Ta = 25°C)**

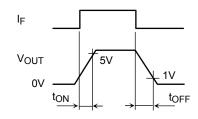
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V <sub>S</sub> = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage	$BV_S$	AC, 1 second in oil	_	5000	_	VIIIIS
		DC, 1 minute in oil	_	5000	_	Vdc

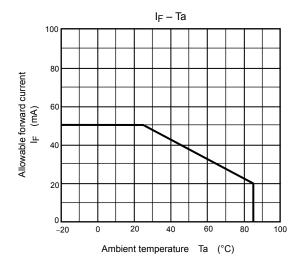
## **Switching Characteristics (Ta = 25°C)**

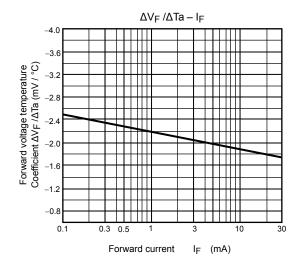
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t <sub>ON</sub>	$I_F$ = 20 mA, $R_{SH}$ = 510 kΩ	_	0.2	_	ms
Turn-off time	toff	$C_L = 1000pF$ (Fig. 1)	_	1	_	ms

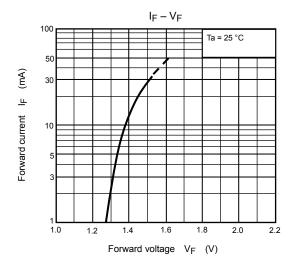
Fig. 1 Switching time test circuit

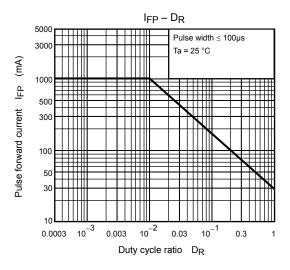




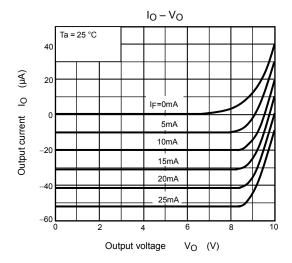


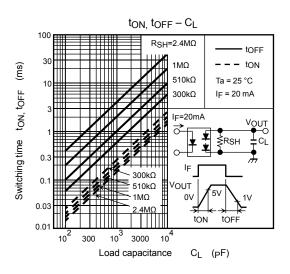


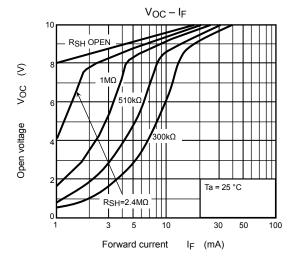


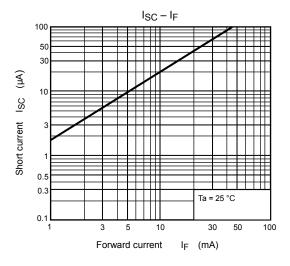


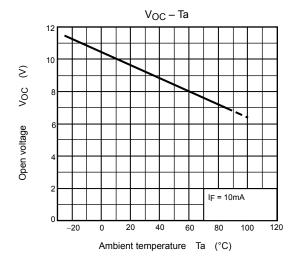
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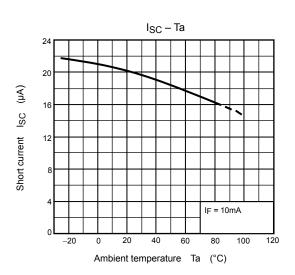












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20070701-EN GENERAL

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